

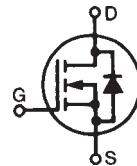
**Polar™ HiPerFET™
Power MOSFET**

(Electrically Isolated Tab)

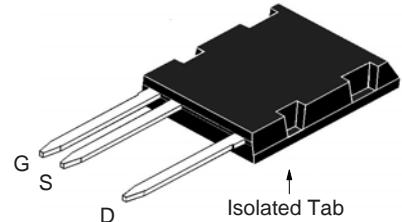
N-Channel Enhancement Mode

Avalanche Rated

Fast Intrinsic Diode

IXFL32N120P

V_{DSS}	=	1200V
I_{D25}	=	24A
$R_{DS(on)}$	\leq	340mΩ
t_{rr}	\leq	300ns

ISOPLUS i5-Pak™

G = Gate D = Drain
S = Source

Features

- Silicon Chip on Direct-Copper-Bond Substrate
 - High Power Dissipation
 - Isolated Mounting Surface
 - 2500V Electrical Isolation
- Avalanche Rated
- Fast Intrinsic Diode

Advantages

- Easy Assembly
- Space Savings
- High Power Density

Applications

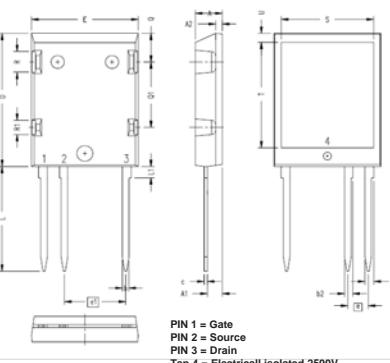
- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- Laser Drivers
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol	Test Conditions	Maximum Ratings		
V_{DSS}	$T_J = 25^\circ\text{C}$ to 150°C	1200	V	
V_{DGR}	$T_J = 25^\circ\text{C}$ to 150°C , $R_{GS} = 1\text{M}\Omega$	1200	V	
V_{GSS}	Continuous	± 30	V	
V_{GSM}	Transient	± 40	V	
I_{D25}	$T_C = 25^\circ\text{C}$	24	A	
I_{DM}	$T_C = 25^\circ\text{C}$, Pulse Width Limited by T_{JM}	100	A	
I_A	$T_C = 25^\circ\text{C}$	16	A	
E_{AS}	$T_C = 25^\circ\text{C}$	2	J	
dv/dt	$I_S \leq I_{DM}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$	20	V/ns	
P_D	$T_C = 25^\circ\text{C}$	520	W	
T_J		-55 ... +150	°C	
T_{JM}		150	°C	
T_{stg}		-55 ... +150	°C	
T_L	Maximum Lead Temperature for Soldering	300	°C	
T_{SOLD}	Plastic Body for 10s	260	°C	
V_{ISOL}	50/60 Hz, RMS, 1 minute	2500	V~	
	$I_{ISOL} \leq 1\text{mA}$ t = 1s	3000	V~	
F_c	Mounting Force	40..120/4.5..27	N/lb.	
Weight		8	g	

Symbol	Test Conditions ($T_J = 25^\circ\text{C}$, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV_{DSS}	$V_{GS} = 0\text{V}$, $I_D = 3\text{mA}$	1200		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 1\text{mA}$	3.5		V
I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0\text{V}$		± 300	nA
I_{DSS}	$V_{DS} = V_{DSS}$, $V_{GS} = 0\text{V}$ Note 2, $T_J = 125^\circ\text{C}$		50	μA
			5	mA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 16\text{A}$, Note 1		340	mΩ

Symbol	Test Conditions (T _J = 25°C Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
g_{fs}	V _{DS} = 20V, I _D = 16A, Note 1	17	29	S
C_{iss}			21	nF
C_{oss}			1105	pF
C_{rss}			77	pF
R _{Gi}	Gate input resistance		0.84	Ω
$t_{d(on)}$	Resistive Switching Times V _{GS} = 10V, V _{DS} = 0.5 • V _{DSS} , I _D = 16A R _G = 1Ω (External)		70	ns
t_r			62	ns
$t_{d(off)}$			88	ns
t_f			51	ns
$Q_{g(on)}$		360		nC
Q_{gs}		130		nC
Q_{gd}		160		nC
R _{thJC}			0.24 °C/W	
R _{thCS}		0.15		°C/W

Source-Drain Diode		Characteristic Values		
T _J = 25°C Unless Otherwise Specified)		Min.	Typ.	Max.
I _s	V _{GS} = 0V			32 A
I _{SM}	Repetitive, Pulse Width Limited by T _{JM}			128 A
V _{SD}	I _F = I _S , V _{GS} = 0V, Note 1			1.5 V
t_{rr}	$I_F = 25A$, -di/dt = 100A/μs V _R = 100V, V _{GS} = 0V		300 ns	
Q _{RM}		1.9		μC
I _{RM}		15.0		A

ISOPLUS i5-Pak™ (IXFL) Outline

SYM	INCHES		MILLIMETER	
	MIN	MAX	MIN	MAX
A	0.190	0.205	4.83	5.21
A1	0.102	0.118	2.59	3.00
A2	0.046	0.055	1.17	1.40
b	0.045	0.055	1.14	1.40
b1	0.063	0.072	1.60	1.83
b2	0.058	0.068	1.47	1.73
c	0.020	0.029	0.51	0.74
D	1.020	1.040	25.91	26.42
E	0.770	0.799	19.56	20.29
e	0.150 BSC		3.81 BSC	
e1	0.450 BSC		11.43 BSC	
L	0.780	0.820	19.81	20.83
L1	0.080	0.102	2.03	2.59
Q	0.210	0.235	5.33	5.97
Q1	0.490	0.513	12.45	13.03
R	0.150	0.180	3.81	4.57
R1	0.100	0.130	2.54	3.30
S	0.668	0.690	16.97	17.53
T	0.801	0.821	20.34	20.85
U	0.065	0.080	1.65	2.03

Notes:

1. Pulse test, t ≤ 300μs, duty cycle, d ≤ 2%.
2. Part must be heatsunk for high-temp Ices measurement.

PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from data gathered during objective characterizations of preliminary engineering lots; but also may yet contain some information supplied during a pre-production design evaluation. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

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IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 7,005,734 B2 7,157,338B2 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692 7,063,975 B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2 7,071,537

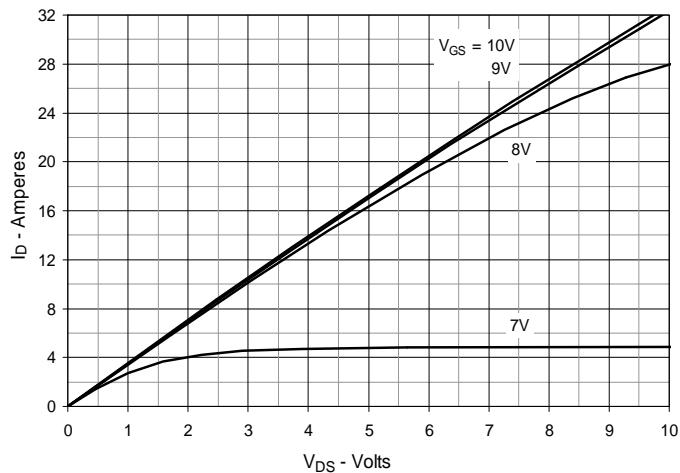
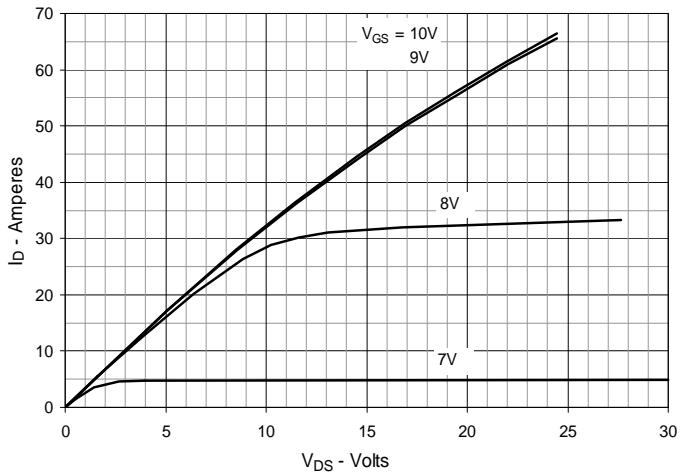
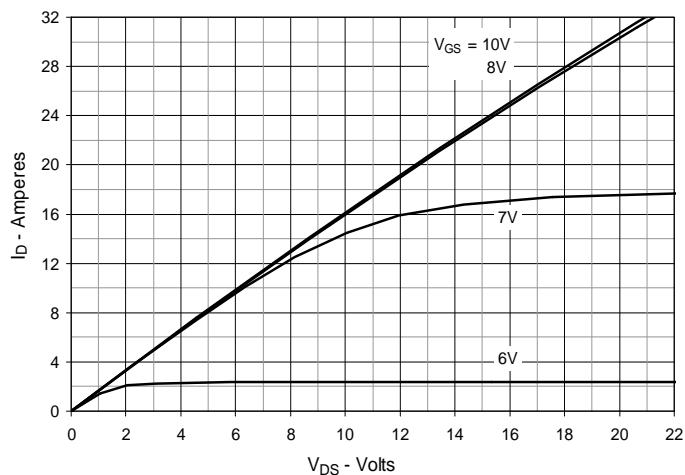
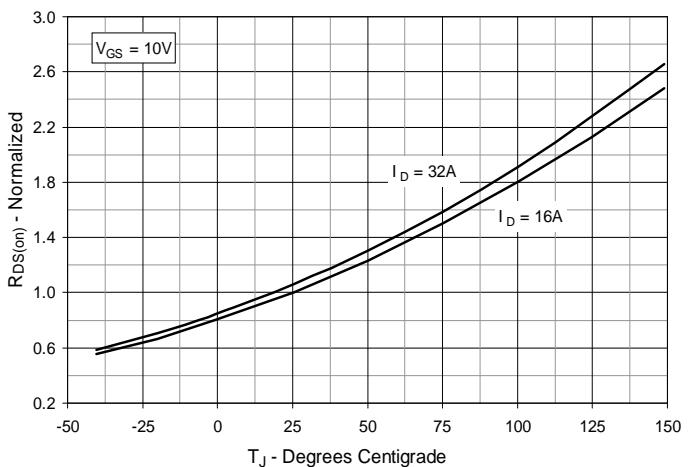
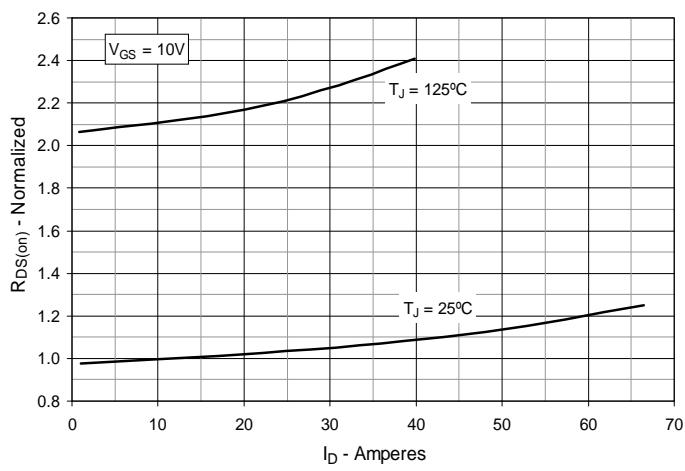
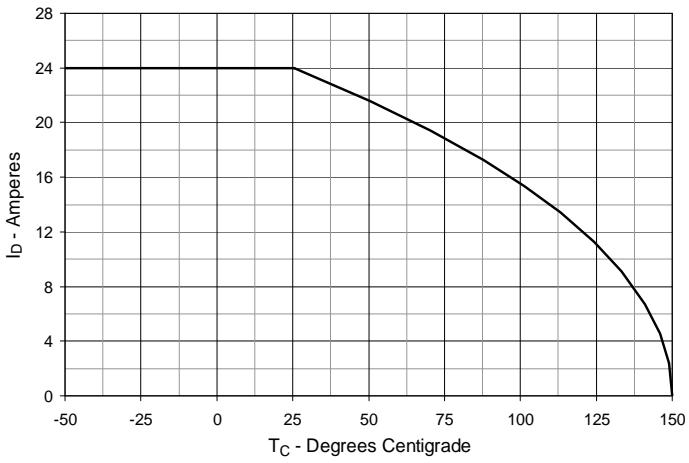
Fig. 1. Output Characteristics @ $T_J = 25^\circ\text{C}$ **Fig. 2. Extended Output Characteristics @ $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics $T_J = 125^\circ\text{C}$** **Fig. 4. $R_{DS(on)}$ Normalized to $I_D = 16A$ Value vs. Junction Temperature****Fig. 5. $R_{DS(on)}$ Normalized to $I_D = 16A$ Value vs. Drain Current****Fig. 6. Maximum Drain Current vs. Case Temperature**

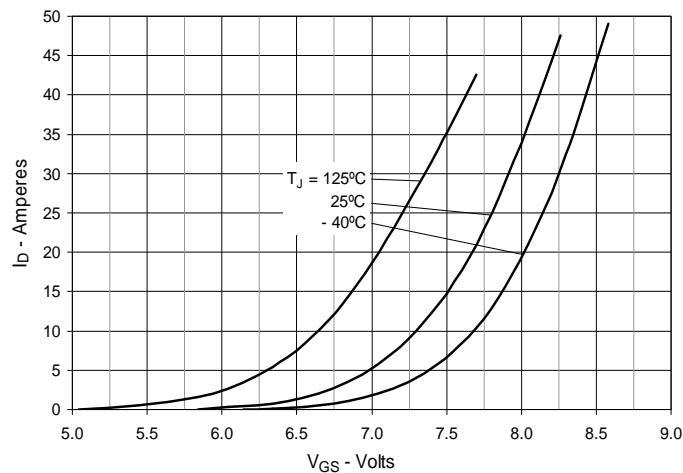
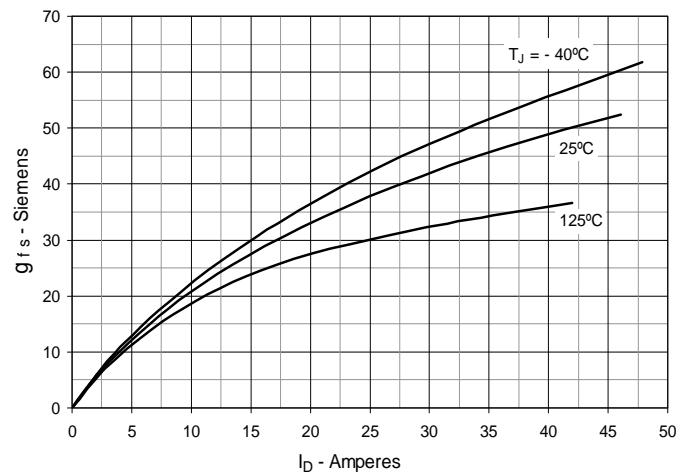
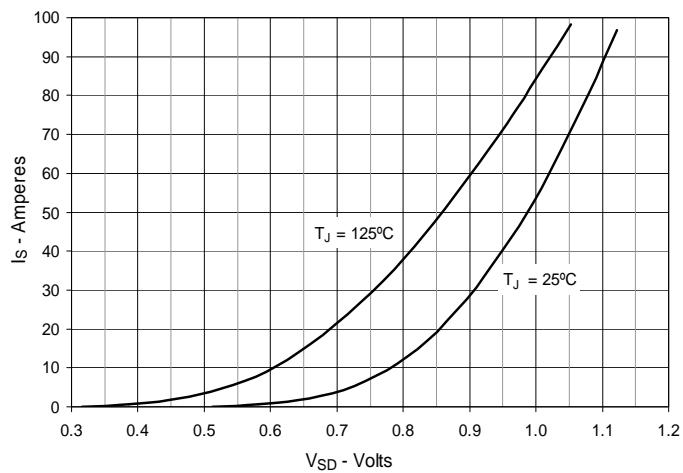
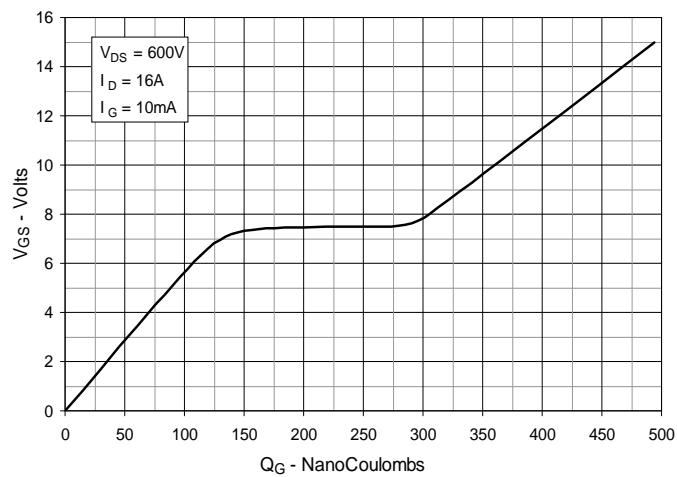
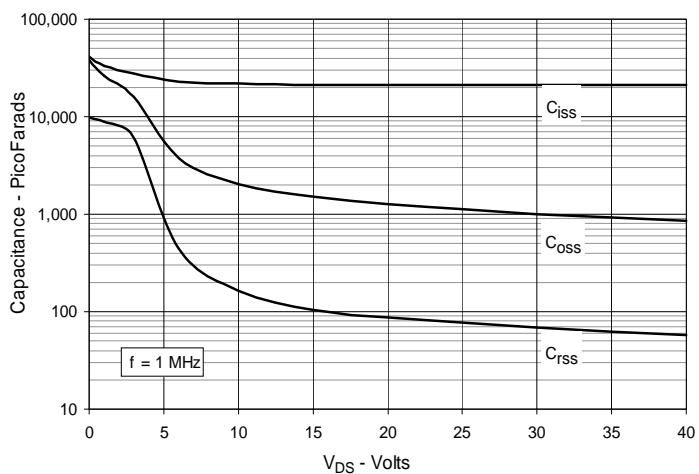
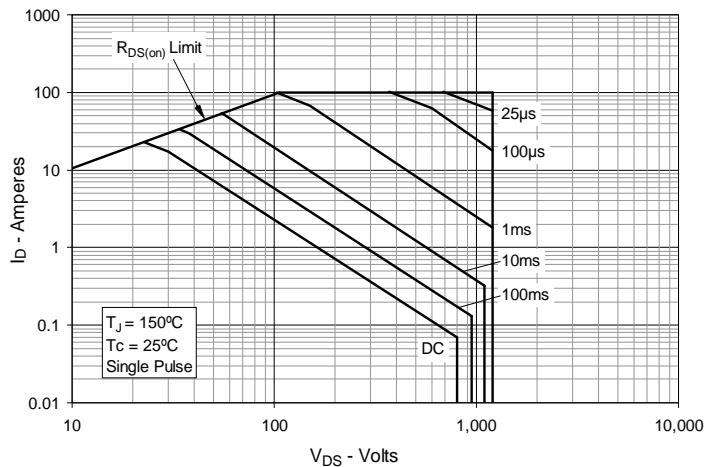
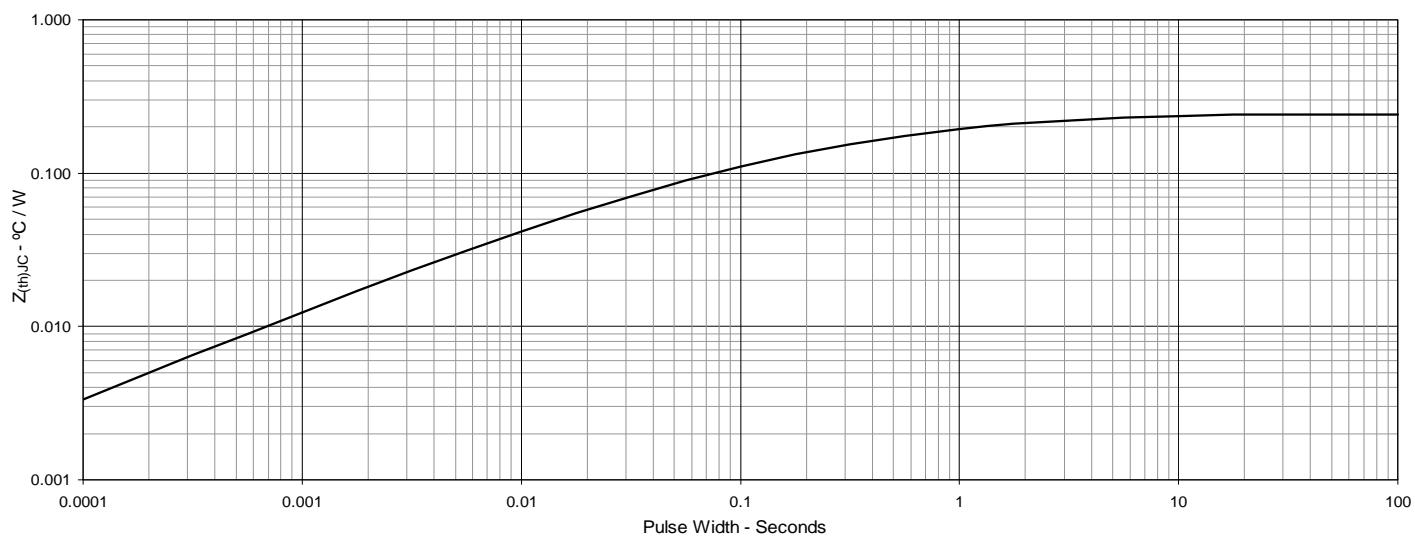
Fig. 7. Input Admittance**Fig. 8. Transconductance****Fig. 9. Forward Voltage Drop of Intrinsic Diode****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Forward-Bias Safe Operating Area**

Fig. 13. Maximum Transient Thermal Impedance



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